



XC74WL34AASR



CMOS Logic

- ◆ CMOS Logic Dual Bus Buffer
- ◆ Operating Voltage Range : 2V ~ 5.5V
- ◆ High Speed Operations : tpd = 2.05ns TYP
- ◆ Low Power Consumption : 1 μ A (max)
- ◆ MSOP-8B Package

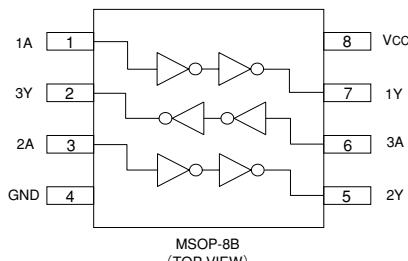
■ Description

XC74WL34AASR is Triple Buffer manufactured using silicon gate CMOS processes. The small quiescent current, which is one of the features of the CMOS logic, gives way to high speed operations which enables LS-TTL.

With wave forming buffers connected internally, stabilized output can be achieved as the series offers high noise immunity.

As the series is integrated into a mini molded, MSOP-8B package, high density mounting is possible.

■ Pin Configuration



■ Applications

- Palmtops
- Digital Equipment

■ Features

- High Speed Operations : tpd = 2.05ns TYP (Vcc=5V)
- Operating Voltage Range: 2V ~ 5.5V
- Low Power Consumption: 1 μ A (max)
- Small Package : MSOP-8B

■ Functions

INPUT	OUTPUT
A	Y
H	H
L	L

H = High Level

L = Low Level

■ Absolute Maximum Ratings

T_a=-40°C ~ 85°C

PARAMETER	SYMBOL	RATINGS	UNITS
Power Supply Voltage	V _{CC}	-0.5~+6.0	V
Input Voltage	V _{IN}	-0.5~+6.0	V
Output Voltage	V _{OUT}	-0.5~V _{CC} +0.5	V
Input Diode Current	I _{IK}	-20	mA
Output Diode Current	I _{OK}	\pm 20	mA
Switch Output Current	I _{OUT}	\pm 25	mA
V _{CC} , GND Current	I _{CC} , I _{GND}	\pm 50	mA
Power Dissipation (Ta=25°C)	P _d	300	mW
Storage Temperature	T _{Stg}	-65~+150	°C

Note : Voltage is all Ground standardized.

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■ Recommended Operating Conditions

PARAMETER	SYMBOL	CONDITIONS			UNITS
Supply Voltage	VCC	2~5.5			V
Input Voltage	VIN	0~5.5			V
Output Voltage	VOUT	0~VCC			V
Operating Temperature	T _{opr}	−40~+85			°C
Input Rise and Fall Time	tr, tf	0~200 (VCC=3.3V)			ns
		0~100 (VCC=5V)			

■ DC Electrical Characteristics

PARAMETER	SYMBOL	CONDITIONS		Ta=25°C			Ta=−40~85°C			UNITS
				MIN	TYP	MAX	MIN	MAX		
Input Voltage	VIH	VCC (V)	2.0 3.0 5.5	1.5	—	—	1.5	—	V	V
				2.1	—	—	2.1	—		
				3.85	—	—	3.85	—		
	VIL	VCC (V)	2.0 3.0 5.5	—	—	0.5	—	0.5	V	V
				—	—	0.9	—	0.9		
				—	—	1.65	—	1.65		
Output Voltage	VOH	VIN=VIH	IOH=−50 μA IOH=−4mA IOH=−8mA	1.9	2.0	—	1.9	—	V	V
				2.9	3.0	—	2.9	—		
				4.4	4.5	—	4.4	—		
				2.58	—	—	2.48	—		
				3.94	—	—	3.80	—		
	VOL	VIN=VIL	IOL=50 μA IOL=4mA IOL=8mA	—	—	0.1	—	0.1	V	V
				—	—	0.1	—	0.1		
				—	—	0.1	—	0.1		
				—	—	0.36	—	0.44		
				—	—	0.36	—	0.44		
Input Current	I _{IN}	0~5.5	VIN=VCC or GND	−0.1	—	0.1	−1.0	1.0	μA	
Quiescent Supply Current	I _{CC}	5.5	VIN=VCC or GND, I _{OUT} =0 μA	—	—	1.0	—	10.0	μA	

■ Switching Electrical Characteristics

PARAMETER	SYMBOL	CONDITIONS		Ta=25°C			Ta=−40~85°C			UNITS
				MIN	TYP	MAX	MIN	MAX		
Propagation Delay Time	t _{PLH}	15pF	3.3	—	2.7	7.1	1	8.5	ns	ns
			5.0	—	2.1	5.5	1	6.5		
	t _{PHL}	50pF	3.3	—	4.1	10.6	1	12	ns	ns
			5.0	—	3.2	7.5	1	8.5		
	t _{PLH}	15pF	3.3	—	2.5	7.1	1	8.5	ns	ns
			5.0	—	2.0	5.5	1	6.5		
	t _{PHL}	50pF	3.3	—	3.9	10.6	1	12	ns	ns
			5.0	—	3.0	7.5	1	8.5		
Input Capacitance	C _{IN}	—	5.0	VIN=VCC or GND	—	2	10	—	10	pF
Power Dissipation Capacitance	C _{pd}	No Load, f=1MHz			—	8.9	—	—	—	pF

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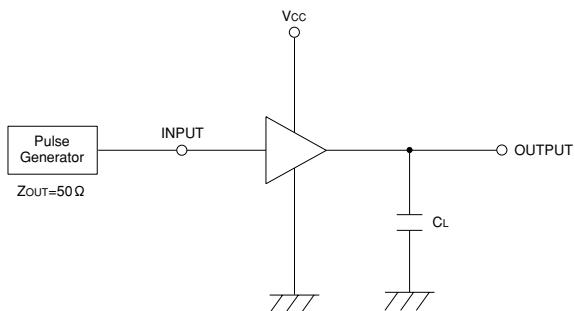
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■Noise Characteristics

PARAMETER	SYMBOL			CONDITIONS	Ta=25°C			UNITS
		CL	Vcc(V)		MIN	TYP	MAX	
Not functioning output maximum dynamic Vol.	VOLP	50pF	5.0		—	0.3	0.8	V
Not functioning output minimum dynamic Vol.	VOLV	50pF	5.0		-0.8	-0.3	—	V
Minimum dynamic ViH	ViHD	50pF	5.0		—	—	3.5	V
Maximum dynamic Vil	ViLD	50pF	5.0		—	—	1.5	V

■Typical Application Circuit



■Waveforms

